SN54SC2T74-SEP Radiation Tolerant, Dual D-Type Flip-Flop With Integrated Translation

1 Features

- Vendor item drawing available, VID V62/23632-01XE
- Total ionizing dose characterized at 30 krad (Si)
  - Total ionizing dose radiation lot acceptance testing (TID RLAT) for every wafer lot to 30 krad (Si)
- Single-event effects (SEE) characterized:
  - Single event latch-up (SEL) immune to linear energy transfer (LET) = 43 MeV-cm2 /mg
  - Single event transient (SET) characterized to 43 MeV-cm2 /mg
- Wide operating range of 1.2 V to 5.5 V
- Single-supply translating gates at 5/3.3/2.5/1.8/1.2 V V_{CC}
  - TTL compatible inputs:
    - Up translation:
      - 1.8-V – Inputs from 1.2 V
      - 2.5-V – Inputs from 1.8 V
      - 3.3-V – Inputs from 1.8 V, 2.5 V
      - 5.0-V – Inputs from 2.5 V, 3.3 V
    - Down translation:
      - 1.2-V – Inputs from 1.8 V, 2.5 V, 3.3 V, 5.0 V
      - 1.8-V – Inputs from 2.5 V, 3.3 V, 5.0 V
      - 2.5-V – Inputs from 3.3 V, 5.0 V
      - 3.3-V – Inputs from 5.0 V
- 5.5 V tolerant input pins
- Output drive up to 25 mA AT 5-V
- Latch-up performance exceeds 250 mA per JESD 17
- Space enhanced plastic (SEP)
  - Controlled baseline
  - Gold bondwire
  - NiPdAu lead finish
  - One assembly and test site
  - One fabrication site
  - Military (–55°C to 125°C) temperature range
  - Extended product life cycle
  - Product traceability
  - Meets NASAs ASTM E595 outgassing specification

2 Applications

- Enable or disable a digital signal
- Controlling an indicator LED
- Translation between communication modules and system controllers

3 Description

The SN54SC2T74-SEP contains two independent D-type positive-edge-triggered flip-flops. A low level at the preset ($\overline{PRE}$) input sets the output high. A low level at the clear ($\overline{CLR}$) input resets the output low. Preset and clear functions are asynchronous and not dependent on the levels of the other inputs. When PRE and CLR are inactive (high), data at the data (D) input meeting the setup time requirements is transferred to the outputs (Q, $\overline{Q}$) on the positive-going edge of the clock (CLK) pulse. Clock triggering occurs at a voltage level and is not directly related to the rise time of the input clock (CLK) signal. Following the hold-time interval, data at the data (D) input can be changed without affecting the levels at the outputs (Q, $\overline{Q}$). The output level is referenced to the supply voltage (V_{CC}) and supports 1.8-V, 2.5-V, 3.3-V, and 5-V CMOS levels.

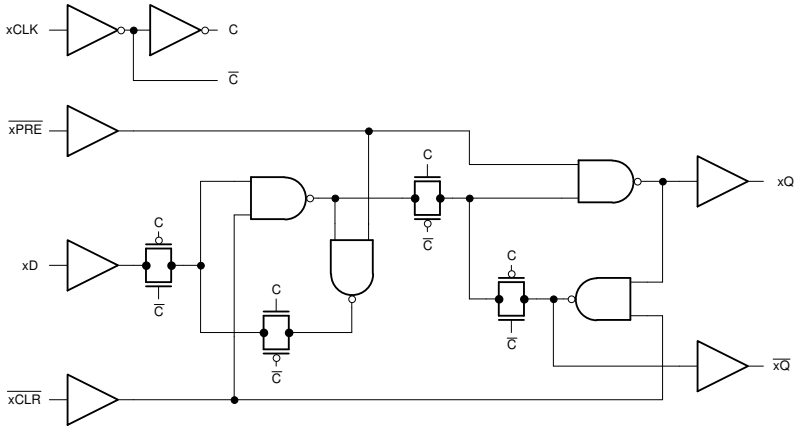
The input is designed with a lower threshold circuit to support up translation for lower voltage CMOS inputs (for example, 1.2 V input to 1.8 V output or 1.8 V input to 3.3 V output). In addition, the 5-V tolerant input pins enable down translation (for example, 3.3 V to 2.5 V output).

Package Information

PART NUMBER	PACKAGE(1)	PACKAGE SIZE(2)	BODY SIZE (NOM)(3)
SN54SC2T74-SEP	PW (TSSOP, 14)	5.00 mm × 6.40 mm	5.00 mm × 4.40 mm

(1) For more information, see Section 11.
(2) The package size (length × width) is a nominal value and includes pins, where applicable
(3) The body size (length × width) is a nominal value and does not include pins.

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.



Simplified Logic Diagram

Copyright © 2023 Texas Instruments Incorporated

Table of Contents

1 Features....1
2 Applications....1
3 Description....1
4 Pin Configuration and Functions....4
5 Specifications....5
5.1 Absolute Maximum Ratings....5
5.2 ESD Ratings....5
5.3 Recommended Operating Conditions....5
5.4 Thermal Information....6
5.5 Electrical Characteristics....6
5.6 Switching Characteristics....7
5.7 Timing Characteristics....8
5.8 Noise Characteristics....9
5.9 Typical Characteristics....10
6 Parameter Measurement Information....13
7 Detailed Description....14
7.1 Overview....14
7.2 Functional Block Diagram....14
7.3 Feature Description....14
7.4 Device Functional Modes....17
8 Application and Implementation....18
8.1 Application Information....18
8.2 Typical Application....18
8.3 Power Supply Recommendations....20
8.4 Layout....21
9 Device and Documentation Support....22
9.1 Documentation Support....22
9.2 Receiving Notification of Documentation Updates....22
9.3 Support Resources....22
9.4 Trademarks....22
9.5 Electrostatic Discharge Caution....22
9.6 Glossary....22
10 Revisiqon History....22
11 Mechanical, Packaging, and Orderable Information....22

Copyright © 2023 Texas Instruments Incorporated

4 Pin Configuration and Functions

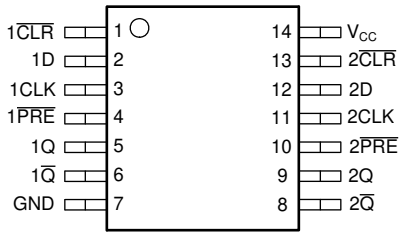


Figure 4-1. PW Package, 14-Pin TSSOP (Top View)

Table 4-1. Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.		
1$\overline{CLR}$	1	Input	Clear for channel 1, active low
1D	2	Input	Data for channel 1
1CLK	3	Input	Clock for channel 1, rising edge triggered
1$\overline{PRE}$	4	Input	Preset for channel 1, active low
1Q	5	Output	Output for channel 1
1$\overline{Q}$	6	Output	Inverted output for channel 1
GND	7	—	Ground
2$\overline{Q}$	8	Output	Inverted output for channel 2
2Q	9	Output	Output for channel 2
2$\overline{PRE}$	10	Input	Preset for channel 2, active low
2CLK	11	Input	Clock for channel 2, rising edge triggered
2D	12	Input	Data for channel 2
2$\overline{CLR}$	13	Input	Clear for channel 2, active low
V_{CC}	14	—	Positive supply

Copyright © 2023 Texas Instruments Incorporated

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		–0.5	7	V
V_I	Input voltage range(2)		–0.5	7	V
V_O	Voltage range applied to any output in the high-impedance or power-off state(2)		–0.5	7	V
V_O	Output voltage range(2)		–0.5	V_{CC} + 0.5	V
I_{IK}	Input clamp current	V_I < -0.5 V		-20	mA
I_{OK}	Output clamp current	V_O < -0.5 V or V_O > V_{CC} + 0.5 V		±20	mA
I_O	Continuous output current	V_O = 0 to V_{CC}		±25	mA
	Continuous output current through V_{CC} or GND			±50	mA
T_{stg}	Storage temperature		-65	150	°C

(1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. Absolute maximum ratings do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If briefly operating outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not sustain damage, but it may not be fully functional. Operating the device in this manner may affect device reliability, functionality, performance, and shorten the device lifetime.
(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±2000	V
		Charged-device model (CDM), per ANSI/ESDA/JEDEC JS-002(2)	±1000	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage		1.2	5.5	V
V_I	Input voltage		0	5.5	V
V_O	Output voltage		0	V_{CC}	V
V_{IH}	High-level input voltage	V_{CC} = 1.2 V to 1.3 V	0.78		V
V_{IH}	High-level input voltage	V_{CC} = 1.65 V to 2 V	1.1		V
		V_{CC} = 2.25 V to 2.75 V	1.28		
		V_{CC} = 3 V to 3.6 V	1.45		
		V_{CC} = 4.5 V to 5.5 V	2		
V_{IL}	Low-Level input voltage	V_{CC} = 1.2 V to 1.3 V		0.18	V
V_{IL}	Low-Level input voltage	V_{CC} = 1.65 V to 2 V		0.5	V
		V_{CC} = 2.25 V to 2.75 V		0.65	
		V_{CC} = 3 V to 3.6 V		0.75	
		V_{CC} = 4.5 V to 5.5 V		0.85	
I_O	Output current	V_{CC} = 1.6 V to 2 V		±3	mA
		V_{CC} = 2.25 V to 2.75 V		±7	
		V_{CC} = 3.3 V to 5.0 V		±15	
I_O	Output Current	V_{CC} = 4.5 V to 5.5 V		±25	mA
Δt/Δv	Input transition rise or fall rate	V_{CC} = 1.6 V to 5.0 V		20	ns/V

Copyright © 2023 Texas Instruments Incorporated

5.3 Recommended Operating Conditions (continued)

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
T_A	Operating free-air temperature	-55	125	°C

5.4 Thermal Information

THERMAL METRIC(1)		SN54SC2T74-SEP PW (TSSOP) 14 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	147.7	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	77.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	90.9	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	27.2	°C/W
Y_{JB}	Junction-to-board characterization parameter	90.2	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

5.5 Electrical Characteristics

over operating free-air temperature range; typical ratings measured at T_A = 25°C (unless otherwise noted).

PARAMETER	TEST CONDITIONS	V_{CC}	MIN	TYP	MAX	UNIT
V_{OH}	I_{OH} = -50 µA	1.2 V to 5.5 V	V_{CC}-0.2			V
	I_{OH}= -50 µA	1.65 V to 5.5 V	V_{CC}-0.1			
	I_{OH} = -1 mA	1.2 V	0.8			
	I_{OH} = -2 mA	1.65 V to 2 V	1.21	1.7(1)		
	I_{OH} = -3 mA	2.25 V to 2.75 V	1.93	2.4(1)		
	I_{OH} = -5.5 mA	3 V to 3.6 V	2.49	3.08(1)		
	I_{OH} = -8 mA	4.5 V to 5.5 V	3.95	4.65(1)		
	I_{OH}= –24 mA	4.5 V to 5.5 V	3.15			
V_{OL}	I_{OL}= 50 µA	1.2 V to 5.5 V			0.1	V
	I_{OL}= 50 µA	1.65 V to 5.5 V			0.1	
	I_{OL} = 1 mA	1.2 V			0.2	
	I_{OL} = 2 mA	1.65 V to 2 V		0.1(1)	0.25	
	I_{OL} = 3 mA	2.25 V to 2.75 V		0.1(1)	0.2	
	I_{OL} = 5.5 mA	3 V to 3.6 V		0.2(1)	0.25	
	I_{OL}= 8 mA	4.5 V to 5.5 V		0.3(1)	0.35	
	I_{OL}= 24 mA	4.5 V to 5.5 V			0.75	
I_I	V_I = 0 V or V_{CC}	0 V to 5.5 V		±0.1	±1	µA
I_{CC}	V_I = V_{CC} or GND, I_O = 0	1.2 V to 5.5 V		2	93	µA
ΔI_{CC}	One input at 0.3 V or 3.4 V, other inputs at 0 or V_{CC}, I_O = 0	5.5 V		1.35	1.5	mA
	One input at 0.3 V or 1.1 V, other inputs at 0 or V_{CC}, I_O = 0	1.8 V			68	µA
C_I	V_I = V_{CC} or GND	5 V		3	5	pF
C_O	V_O = V_{CC} or GND	5 V		5	8	pF
C_{PD} (2) (3)	C_L = 50 pF, F = 10 MHz	1.2 V to 5.5 V		11	25	pF

(1) Typical value at nearest nominal voltage (1.8 V, 2.5 V, 3.3 V, and 5 V)
(2) C_{PD} is used to determine the dynamic power consumption, per channel.

Copyright © 2023 Texas Instruments Incorporated

(3) $P_D = V_{CC}{}^2 x F_I x (C_{PD} + C_L)$ where F_I = input frequency, C_L = output load capacitance, V_{CC} = supply voltage.

5.6 Switching Characteristics

over operating free-air temperature range; typical ratings measured at T_A = 25°C (unless otherwise noted).

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	V_{CC}	MIN	TYP	MAX	UNIT
F_{MAX}			C_L = 15 pF	1.2 V	5.6	18.8		MHz
F_{MAX}			C_L = 50 pF	1.2 V	5.6	15.0		MHz
t_{PLH}	$\overline{PRE}$ or $\overline{CLR}$	Q or $\overline{Q}$	C_L = 15 pF	1.2 V		75.4	138.1	nS
t_{PHL}	$\overline{PRE}$ or $\overline{CLR}$	Q or $\overline{Q}$	C_L = 15 pF	1.2 V		102.2	158.9	nS
t_{PLH}	CLK	Q or $\overline{Q}$	C_L = 15 pF	1.2 V		65.5	104.7	nS
t_{PHL}	CLK	Q or $\overline{Q}$	C_L = 15 pF	1.2 V		79.4	126.6	nS
t_{PLH}	$\overline{PRE}$ or $\overline{CLR}$	Q or $\overline{Q}$	C_L = 50 pF	1.2 V		56.0	148.9	nS
t_{PHL}	$\overline{PRE}$ or $\overline{CLR}$	Q or $\overline{Q}$	C_L = 50 pF	1.2 V		67.8	170.7	nS
t_{PLH}	CLK	Q or $\overline{Q}$	C_L = 50 pF	1.2 V		44.7	115.5	nS
t_{PHL}	CLK	Q or $\overline{Q}$	C_L = 50 pF	1.2 V		51.1	138.3	nS
F_{MAX}			C_L = 15 pF	1.8 V	17.6	38.1		MHz
F_{MAX}			C_L = 50 pF	1.8 V	17.6	38.1		MHz
t_{PLH}	$\overline{PRE}$ or $\overline{CLR}$	Q or $\overline{Q}$	C_L = 15 pF	1.8 V		20.9	46.6	nS
t_{PHL}	$\overline{PRE}$ or $\overline{CLR}$	Q or $\overline{Q}$	C_L = 15 pF	1.8 V		25.3	47.2	nS
t_{PLH}	CLK	Q or $\overline{Q}$	C_L = 15 pF	1.8 V		15.3	33.2	nS
t_{PHL}	CLK	Q or $\overline{Q}$	C_L = 15 pF	1.8 V		16.6	32.3	nS
t_{PLH}	$\overline{PRE}$ or $\overline{CLR}$	Q or $\overline{Q}$	C_L = 50 pF	1.8 V		23.2	50.2	nS
t_{PHL}	$\overline{PRE}$ or $\overline{CLR}$	Q or $\overline{Q}$	C_L = 50 pF	1.8 V		27.7	50.6	nS
t_{PLH}	CLK	Q or $\overline{Q}$	C_L = 50 pF	1.8 V		17.5	37.0	nS
t_{PHL}	CLK	Q or $\overline{Q}$	C_L = 50 pF	1.8 V		18.6	35.7	nS
F_{MAX}			C_L = 15 pF	2.5 V	23.2	50.5		MHz
F_{MAX}			C_L = 50 pF	2.5 V	23.2	50.5		MHz
t_{PLH}	$\overline{PRE}$ or $\overline{CLR}$	Q or $\overline{Q}$	C_L = 15 pF	2.5 V		13.3	27.1	nS
t_{PHL}	$\overline{PRE}$ or $\overline{CLR}$	Q or $\overline{Q}$	C_L = 15 pF	2.5 V		13.9	27.3	nS
t_{PLH}	CLK	Q or $\overline{Q}$	C_L = 15 pF	2.5 V		8.4	20.1	nS
t_{PHL}	CLK	Q or $\overline{Q}$	C_L = 15 pF	2.5 V		9.3	17.9	nS
t_{PLH}	$\overline{PRE}$ or $\overline{CLR}$	Q or $\overline{Q}$	C_L = 50 pF	2.5 V		14.8	29.3	nS
t_{PHL}	$\overline{PRE}$ or $\overline{CLR}$	Q or $\overline{Q}$	C_L = 50 pF	2.5 V		15.3	29.3	nS
t_{PLH}	CLK	Q or $\overline{Q}$	C_L = 50 pF	2.5 V		9.9	22.5	nS
t_{PHL}	CLK	Q or $\overline{Q}$	C_L = 50 pF	2.5 V		10.4	19.9	nS
F_{MAX}			C_L = 15 pF	3.3 V	34.3	56.7		MHz
F_{MAX}			C_L = 50 pF	3.3 V	34.3	56.7		MHz
t_{PLH}	$\overline{PRE}$ or $\overline{CLR}$	Q or $\overline{Q}$	C_L = 15 pF	3.3 V		9.8	19.2	nS
t_{PHL}	$\overline{PRE}$ or $\overline{CLR}$	Q or $\overline{Q}$	C_L = 15 pF	3.3 V		10.1	19.2	nS
t_{PLH}	CLK	Q or $\overline{Q}$	C_L = 15 pF	3.3 V		6.1	14.5	nS
t_{PHL}	CLK	Q or $\overline{Q}$	C_L = 15 pF	3.3 V		6.8	12.4	nS
t_{PLH}	$\overline{PRE}$ or $\overline{CLR}$	Q or $\overline{Q}$	C_L = 50 pF	3.3 V		10.9	20.8	nS
t_{PHL}	$\overline{PRE}$ or $\overline{CLR}$	Q or $\overline{Q}$	C_L = 50 pF	3.3 V		11.1	20.7	nS
t_{PLH}	CLK	Q or $\overline{Q}$	C_L = 50 pF	3.3 V		7.2	16.4	nS
t_{PHL}	CLK	Q or $\overline{Q}$	C_L = 50 pF	3.3 V		7.6	14.0	nS
F_{MAX}			C_L = 15 pF	5 V	42.8	66.2		MHz

Copyright © 2023 Texas Instruments Incorporated

5.6 Switching Characteristics (continued)

over operating free-air temperature range; typical ratings measured at T_A = 25°C (unless otherwise noted).

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	V_{CC}	MIN	TYP	MAX	UNIT
F_{MAX}			C_L = 50 pF	5 V	42.8	59.4		MHz
t_{PLH}	$\overline{PRE}$ or $\overline{CLR}$	Q or Q	C_L = 15 pF	5 V		7.0	12.8	nS
t_{PHL}	$\overline{PRE}$ or $\overline{CLR}$	Q or Q	C_L = 15 pF	5 V		6.9	12.7	nS
t_{PLH}	CLK	Q or Q	C_L = 15 pF	5 V		5.0	9.8	nS
t_{PHL}	CLK	Q or Q	C_L = 15 pF	5 V		5.3	9.1	nS
t_{PLH}	$\overline{PRE}$ or $\overline{CLR}$	Q or Q	C_L = 50 pF	5 V		7.8	14.0	nS
t_{PHL}	$\overline{PRE}$ or $\overline{CLR}$	Q or Q	C_L = 50 pF	5 V		7.8	13.7	nS
t_{PLH}	CLK	Q or Q	C_L = 50 pF	5 V		5.7	11.2	nS
t_{PHL}	CLK	Q or Q	C_L = 50 pF	5 V		5.9	10.0	nS

5.7 Timing Characteristics

over operating free-air temperature range; typical ratings measured at T_A = 25°C (unless otherwise noted).

PARAMETER	DESCRIPTION	CONDITION	V_{CC}	MIN	MAX	UNIT
t_w	Pulse Duration	$\overline{PRE}$ or $\overline{CLR}$ low	1.2 V	15		nS
t_w	Pulse Duration	CLK high or low	1.2 V	15		nS
t_{su}	Setup time before CLK↑	Data	1.2 V	33		nS
t_{su}	Setup time before CLK↑	$\overline{PRE}$ or $\overline{CLR}$ inactive	1.2 V	12		nS
t_h	Hold time	Data after CLK↑	1.2 V	0.5		nS
t_w	Pulse Duration	$\overline{PRE}$ or $\overline{CLR}$ low	1.8 V	12.9		nS
t_w	Pulse Duration	CLK high or low	1.8 V	12.1		nS
t_{su}	Setup time before CLK↑	Data	1.8 V	22.1		nS
t_{su}	Setup time before CLK↑	$\overline{PRE}$ or $\overline{CLR}$ inactive	1.8 V	10.7		nS
t_h	Hold time	Data after CLK↑	1.8 V	0.5		nS
t_w	Pulse Duration	$\overline{PRE}$ or $\overline{CLR}$ low	2.5 V	8.3		nS
t_w	Pulse Duration	CLK high or low	2.5 V	7.9		nS
t_{su}	Setup time before CLK↑	Data	2.5 V	15.4		nS
t_{su}	Setup time before CLK↑	$\overline{PRE}$ or $\overline{CLR}$ inactive	2.5 V	7.2		nS
t_h	Hold time	Data after CLK↑	2.5 V	0.5		nS
t_w	Pulse Duration	$\overline{PRE}$ or $\overline{CLR}$ low	3.3 V	7.1		nS
t_w	Pulse Duration	CLK high or low	3.3 V	7		nS
t_{su}	Setup time before CLK↑	Data	3.3 V	12.4		nS
t_{su}	Setup time before CLK↑	$\overline{PRE}$ or $\overline{CLR}$ inactive	3.3 V	6		nS
t_h	Hold time	Data after CLK↑	3.3 V	0.5		nS
t_w	Pulse Duration	$\overline{PRE}$ or $\overline{CLR}$ low	5.0 V	6.6		nS
t_w	Pulse Duration	CLK high or low	5.0 V	6.4		nS
t_{su}	Setup time before CLK↑	Data	5.0 V	9.5		nS
t_{su}	Setup time before CLK↑	$\overline{PRE}$ or $\overline{CLR}$ inactive	5.0 V	6.3		nS
t_h	Hold time	Data after CLK↑	5.0 V	0.5		nS

Copyright © 2023 Texas Instruments Incorporated

5.8 Noise Characteristics

VCC = 5 V, CL = 50 pF, TA = 25°C

PARAMETER	DESCRIPTION	MIN	TYP	MAX	UNIT
$V_{OL(P)}$	Quiet output, maximum dynamic V_{OL}		1	1.2	V
$V_{OL(V)}$	Quiet output, minimum dynamic V_{OL}	-0.8	-0.3		V
$V_{OH(V)}$	Quiet output, minimum dynamic V_{OH}	4.4	5		V
$V_{IH(D)}$	High-level dynamic input voltage	2.1			V
$V_{IL(D)}$	Low-level dynamic input voltage			0.5	V

Copyright © 2023 Texas Instruments Incorporated

5.9 Typical Characteristics

T_A = 25°C (unless otherwise noted)

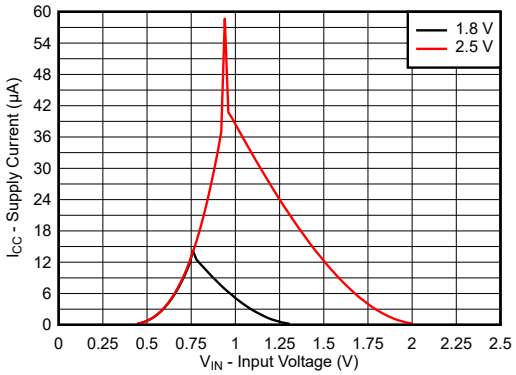


Figure 5-1. Supply Current Across Input Voltage 1.8-V and 2.5-V Supply

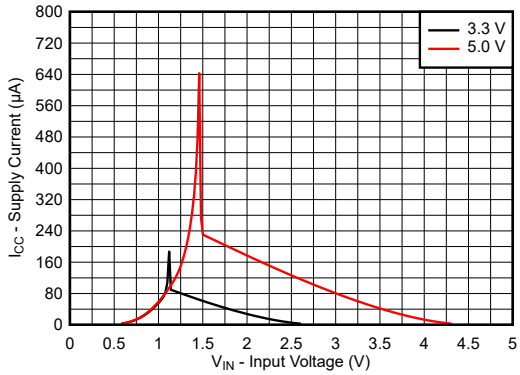


Figure 5-2. Supply Current Across Input Voltage 3.3-V and 5.0-V Supply

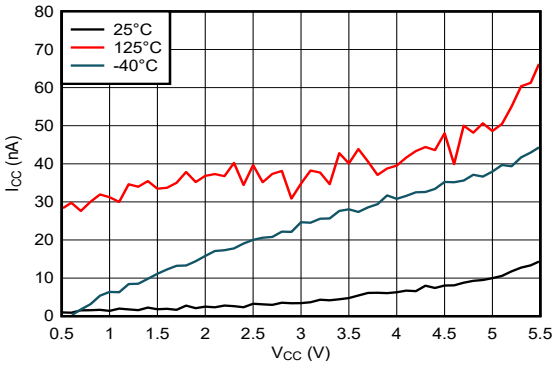


Figure 5-3. Supply Current Across Supply Voltage

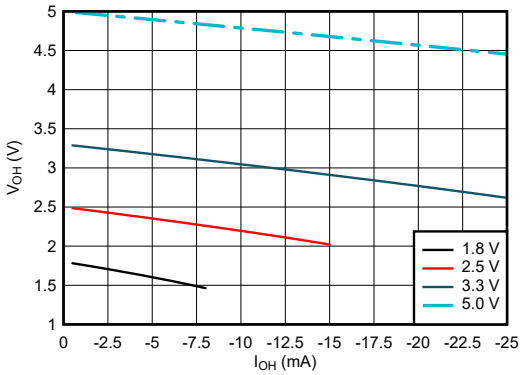


Figure 5-4. Output Voltage vs Current in HIGH State

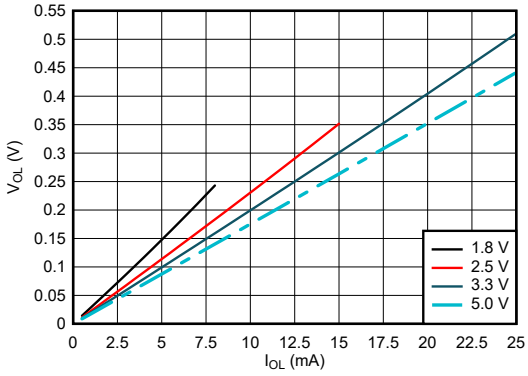


Figure 5-5. Output Voltage vs Current in LOW State

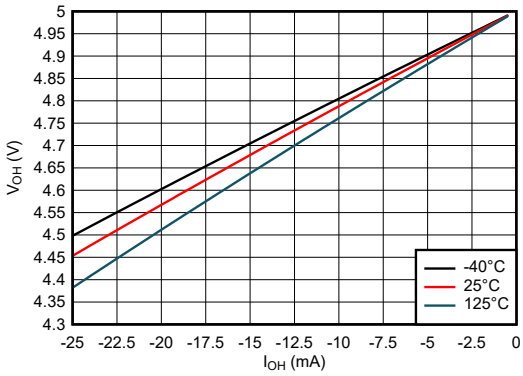


Figure 5-6. Output Voltage vs Current in HIGH State; 5-V Supply

Copyright © 2023 Texas Instruments Incorporated

5.9 Typical Characteristics (continued)

T_A = 25°C (unless otherwise noted)

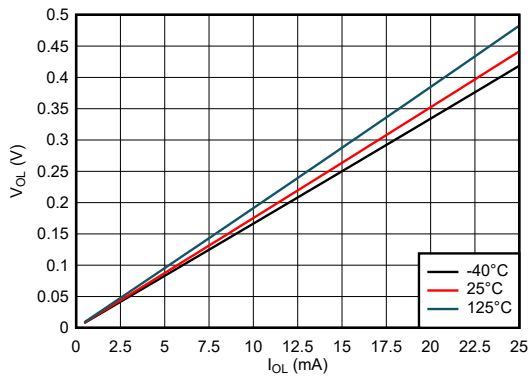


Figure 5-7. Output Voltage vs Current in LOW State; 5-V Supply

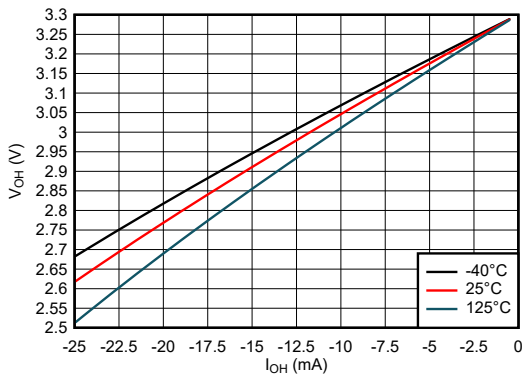


Figure 5-8. Output Voltage vs Current in HIGH State; 3.3-V Supply

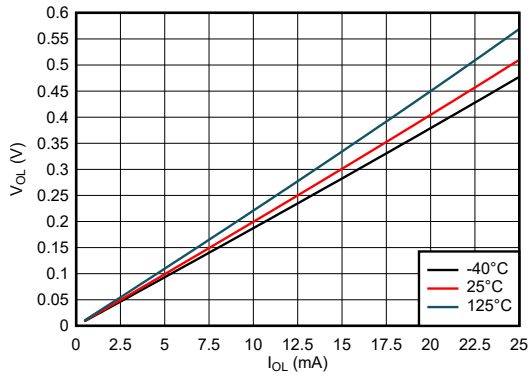


Figure 5-9. Output Voltage vs Current in LOW State; 3.3-V Supply

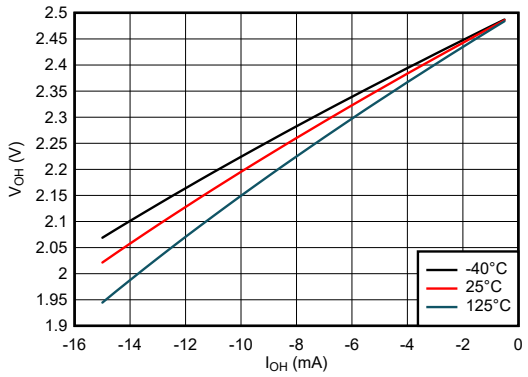


Figure 5-10. Output Voltage vs Current in HIGH State; 2.5-V Supply

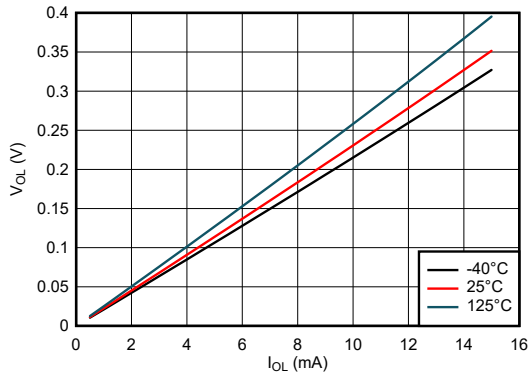


Figure 5-11. Output Voltage vs Current in LOW State; 2.5-V Supply

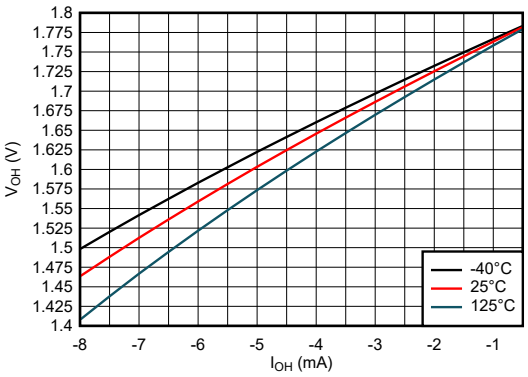


Figure 5-12. Output Voltage vs Current in HIGH State; 1.8-V Supply

Copyright © 2023 Texas Instruments Incorporated

5.9 Typical Characteristics (continued)

T_A = 25°C (unless otherwise noted)

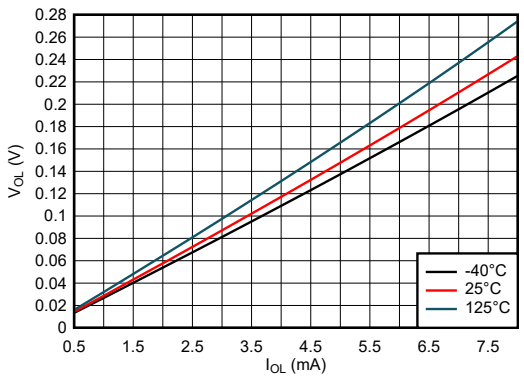


Figure 5-13. Output Voltage vs Current in LOW State; 1.8-V Supply

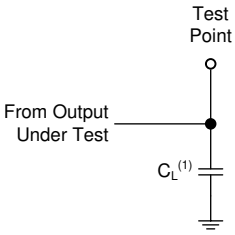
Copyright © 2023 Texas Instruments Incorporated

6 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, Z_O = 50 Ω, t_t< 2.5 ns.

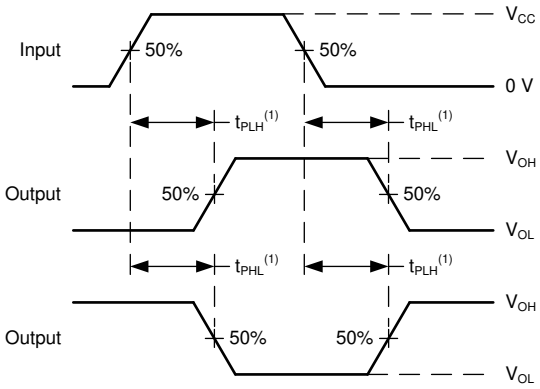
For clock inputs, f_{max} is measured when the input duty cycle is 50%.

The outputs are measured one at a time with one input transition per measurement.



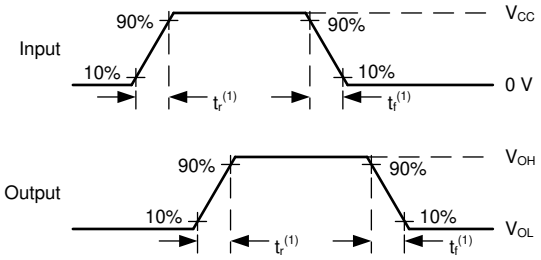
(1) C_L includes probe and test-fixture capacitance.

Figure 6-1. Load Circuit for Push-Pull Outputs



(1) The greater between t_{PLH} and t_{PHL} is the same as t_{pd}.

Figure 6-2. Voltage Waveforms Propagation Delays



(1) The greater between t_r and t_f is the same as t_t.

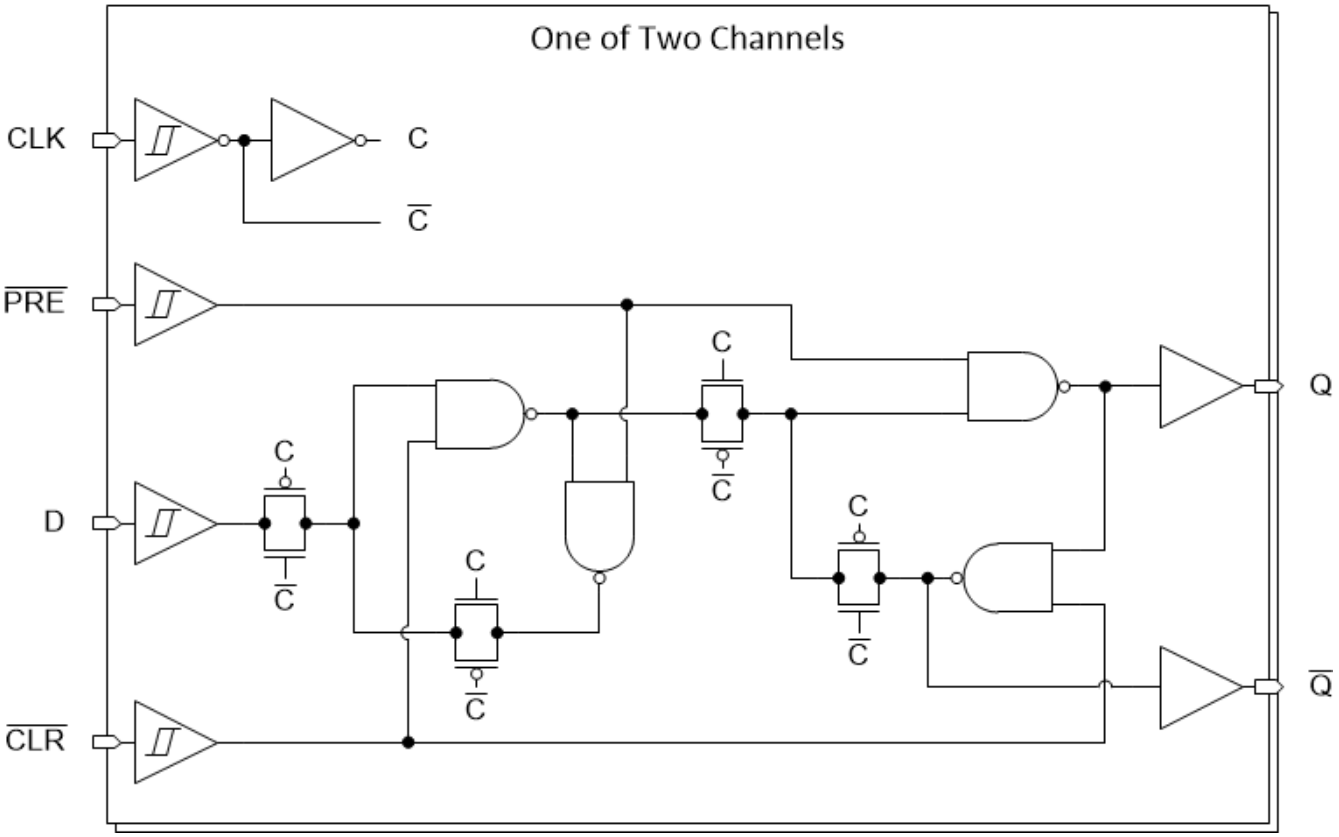
Figure 6-3. Voltage Waveforms, Input and Output Transition Times

7 Detailed Description

7.1 Overview

The SN54SC2T74-SEP contains a single buffer with extended voltage operation to allow for level translation. The buffer performs the Boolean function Y = A in positive logic. The output level is referenced to the supply voltage (V_{CC}) and supports 1.8-V, 2.5-V, 3.3-V, and 5-V CMOS levels.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Balanced CMOS Push-Pull Outputs

This device includes balanced CMOS push-pull outputs. The term *balanced* indicates that the device can sink and source similar currents. The drive capability of this device may create fast edges into light loads so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. It is important for the output power of the device to be limited to avoid damage due to overcurrent. The electrical and thermal limits defined in the *Absolute Maximum Ratings* must be followed at all times.

Unused push-pull CMOS outputs should be left disconnected.

7.3.2 Clamp Diode Structure

As Figure 7-1 shows, the outputs to this device have both positive and negative clamping diodes, and the inputs to this device have negative clamping diodes only.

CAUTION

Voltages beyond the values specified in the *Absolute Maximum Ratings* table can cause damage to the device. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

Copyright © 2023 Texas Instruments Incorporated

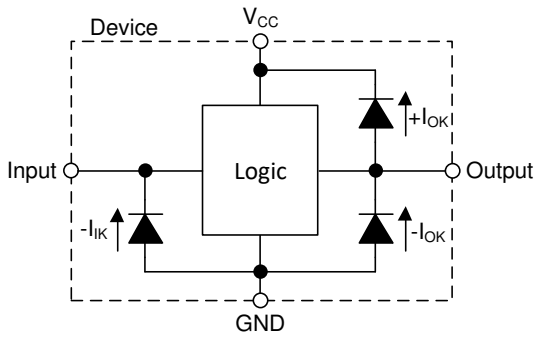


Figure 7-1. Electrical Placement of Clamping Diodes for Each Input and Output

7.3.3 SCxT Enhanced Input Voltage

The SN54SC2T74-SEP belongs to TI's SCxT family of logic devices with integrated voltage level translation. This family of devices was designed with reduced input voltage thresholds to support up-translation, and inputs tolerant of signals with up to 5.5 V levels to support down-translation. The output voltage will always be referenced to the supply voltage (V_{CC}), as described in the *Electrical Characteristics* table. For proper functionality, input signals must remain at or below the specified $V_{IH(MIN)}$ level for a HIGH input state, and at or below the specified $V_{IL(MAX)}$ for a LOW input state. Figure 7-2 shows the typical V_{IH} and V_{IL} levels for the SCxT family of devices, as well as the voltage levels for standard CMOS devices for comparison.

The inputs are high impedance and are typically modeled as a resistor in parallel with the input capacitance given in the *Electrical Characteristics*. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings*, and the maximum input leakage current, given in the *Electrical Characteristics*, using Ohm's law (R = V ÷ I).

The inputs require the input signals to transition between valid logic states quickly, as defined by the input transition time or rate in the *Recommended Operating Conditions* table. Failing to meet this specification will result in excessive power consumption and can cause oscillations. More details can be found in the *Implications of Slow or Floating CMOS Inputs* application report.

Do not leave inputs floating at any time during operation. Unused inputs must be terminated at V_{CC} or GND. If a system will not be actively driving an input at all times, a pull-up or pull-down resistor can be added to provide a valid input voltage during these times. The resistor value will depend on multiple factors; however, a 10-kΩ resistor is recommended and will typically meet all requirements.

Copyright © 2023 Texas Instruments Incorporated

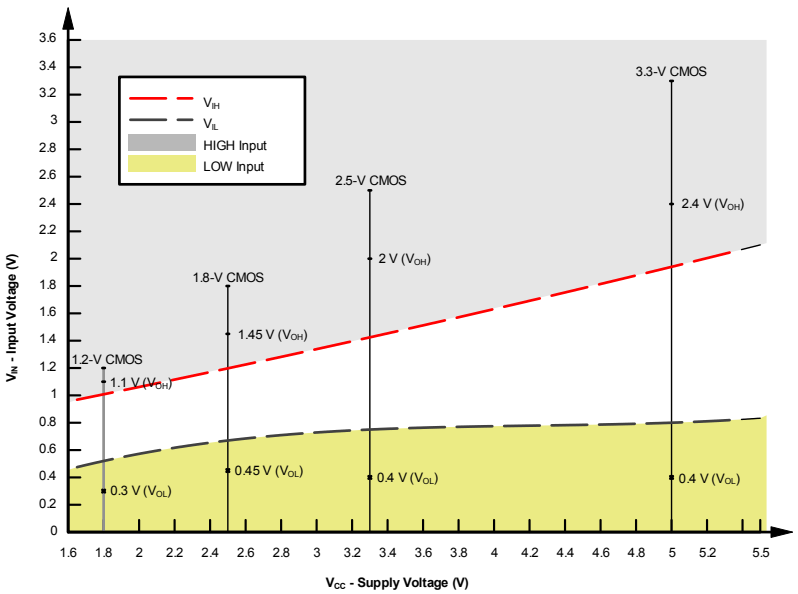


Figure 7-2. SCxT Input Voltage Levels

7.3.3.1 Down Translation

Signals can be translated down using the SN54SC2T74-SEP. The voltage applied at the V_{CC} will determine the output voltage and the input thresholds as described in the *Recommended Operating Conditions* and *Electrical Characteristics* tables.

When connected to a high-impedance input, the output voltage will be approximately V_{CC} in the HIGH state, and 0 V in the LOW state. Ensure that the input signals in the HIGH state are between $V_{IH(MIN)}$ and 5.5 V, and input signals in the LOW state are lower than $V_{IL(MAX)}$ as shown in Figure 7-2.

For example, standard CMOS inputs for devices operating at 5.0 V, 3.3 V or 2.5 V can be down-translated to match 1.8 V CMOS signals when operating from 1.8-V V_{CC}. See Figure 7-3.

Down Translation Combinations are as follows:

- 1.8-V V_{CC} – Inputs from 2.5 V, 3.3 V, and 5.0 V
- 2.5-V V_{CC} – Inputs from 3.3 V and 5.0 V
- 3.3-V V_{CC} – Inputs from 5.0 V

7.3.3.2 Up Translation

Input signals can be up translated using the SN54SC2T74-SEP. The voltage applied at V_{CC} will determine the output voltage and the input thresholds as described in the *Recommended Operating Conditions* and *Electrical Characteristics* tables. When connected to a high-impedance input, the output voltage will be approximately V_{CC} in the HIGH state, and 0 V in the LOW state.

The inputs have reduced thresholds that allow for input HIGH state levels which are much lower than standard values. For example, standard CMOS inputs for a device operating at a 5-V supply will have a $V_{IH(MIN)}$ of 3.5 V. For the SN54SC2T74-SEP, $V_{IH(MIN)}$ with a 5-V supply is only 2 V, which would allow for up-translation from a typical 2.5-V to 5-V signals.

As shown in Figure 7-3, ensure that the input signals in the HIGH state are above $V_{IH(MIN)}$ and input signals in the LOW state are lower than $V_{IL(MAX)}$.

Up Translation Combinations are as follows:

- 1.8-V V_{CC} – Inputs from 1.2 V
- 2.5-V V_{CC} – Inputs from 1.8 V
- 3.3-V V_{CC} – Inputs from 1.8 V and 2.5 V

Copyright © 2023 Texas Instruments Incorporated

- 5.0-V V_{CC} – Inputs from 2.5 V and 3.3 V

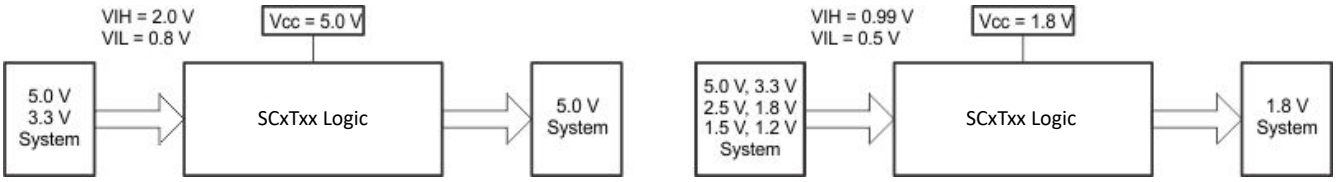


Figure 7-3. SCxT Up and Down Translation Example

7.4 Device Functional Modes

Table 7-1 is the function table for the SN54SC2T74-SEP.

Table 7-1. Function Table

INPUTS(1)				OUTPUTS	
$\overline{PRE}$	$\overline{CLR}$	CLK	D	Q	$\overline{Q}$
L	H	X	X	H	L
H	L	X	X	L	H
L	L	X	X	H(1)	H(1)
H	H	↑	H	H	L
H	H	↑	L	L	H
H	H	L	X	Q_0	$\overline{Q}_0$

(1) H = high voltage level, L = low voltage level, X = do not care, Z = high impedance

Copyright © 2023 Texas Instruments Incorporated

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

Figure 8-1 shows how the SN54SC2T74-SEP is used to up-translate a 1.8-V signal to 3.3 V to drive an LED in this application. The SN54SC2T74-SEP does not limit the output current, so an added output resistor is used to provide the appropriate current limiting. The resistor value (R) should be determined by the LED's forward voltage (V_D) and the desired forward current through the LED (I_D) using this equation: $R = (V_{CC} - V_D)/I_D$.

8.2 Typical Application

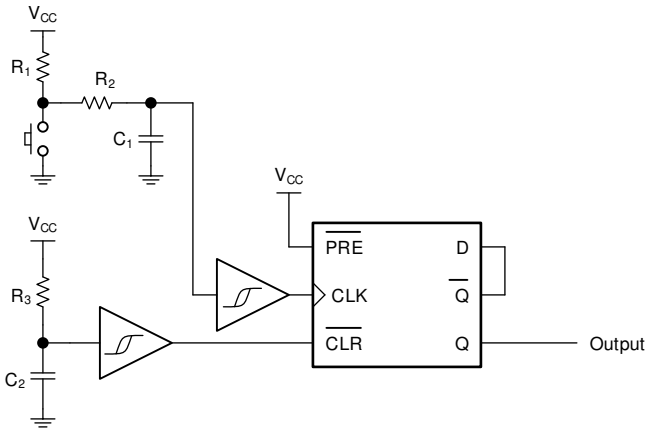


Figure 8-1. Typical Application Block Diagram

8.2.1 Design Requirements

8.2.1.1 Power Considerations

Ensure the desired supply voltage is within the range specified in the *Recommended Operating Conditions*. The supply voltage sets the device's electrical characteristics as described in the *Electrical Characteristics* section.

The positive voltage supply must be capable of sourcing current equal to the total current to be sourced by all outputs of the SN54SC2T74-SEP plus the maximum static supply current, I_{CC}, listed in the *Electrical Characteristics*, and any transient current required for switching. The logic device can only source as much current that is provided by the positive supply source. Be sure to not exceed the maximum total current through V_{CC} listed in the *Absolute Maximum Ratings*.

The ground must be capable of sinking current equal to the total current to be sunk by all outputs of the SN54SC2T74-SEP plus the maximum supply current, I_{CC}, listed in the *Electrical Characteristics*, and any transient current required for switching. The logic device can only sink as much current that can be sunk into its ground connection. Be sure to not exceed the maximum total current through GND listed in the *Absolute Maximum Ratings*.

The SN54SC2T74-SEP can drive a load with a total capacitance less than or equal to 50 pF while still meeting all of the data sheet specifications. Larger capacitive loads can be applied; however, it is not recommended to exceed 50 pF.

Copyright © 2023 Texas Instruments Incorporated

The SN54SC2T74-SEP can drive a load with total resistance described by $R_L \geq V_O / I_O$, with the output voltage and current defined in the *Electrical Characteristics* table with V_{OH} and V_{OL}. When outputting in the HIGH state, the output voltage in the equation is defined as the difference between the measured output voltage and the supply voltage at the V_{CC} pin.

Total power consumption can be calculated using the information provided in *CMOS Power Consumption and Cpd Calculation*.

Thermal increase can be calculated using the information provided in *Thermal Characteristics of Standard Linear and Logic (SLL) Packages and Devices*.

CAUTION

The maximum junction temperature, $T_{J(max)}$ listed in the *Absolute Maximum Ratings*, is an additional limitation to prevent damage to the device. Do not violate any values listed in the *Absolute Maximum Ratings*. These limits are provided to prevent damage to the device.

8.2.1.2 Input Considerations

Input signals must cross $V_{IL(max)}$ to be considered a logic LOW, and $V_{IH(min)}$ to be considered a logic HIGH. Do not exceed the maximum input voltage range found in the *Absolute Maximum Ratings*.

Unused inputs must be terminated to either V_{CC} or ground. The unused inputs can be directly terminated if the input is completely unused, or they can be connected with a pull-up or pull-down resistor if the input will be used sometimes, but not always. A pull-up resistor is used for a default state of HIGH, and a pull-down resistor is used for a default state of LOW. The drive current of the controller, leakage current into the SN54SC2T74-SEP (as specified in the *Electrical Characteristics*), and the desired input transition rate limits the resistor size. A 10-kΩ resistor value is often used due to these factors.

The SN54SC2T74-SEP has CMOS inputs and thus requires fast input transitions to operate correctly, as defined in the *Recommended Operating Conditions* table. Slow input transitions can cause oscillations, additional power consumption, and reduction in device reliability.

Refer to the *Feature Description* section for additional information regarding the inputs for this device.

8.2.1.3 Output Considerations

The positive supply voltage is used to produce the output HIGH voltage. Drawing current from the output will decrease the output voltage as specified by the V_{OH} specification in the *Electrical Characteristics*. The ground voltage is used to produce the output LOW voltage. Sinking current into the output will increase the output voltage as specified by the V_{OL} specification in the *Electrical Characteristics*.

Push-pull outputs that could be in opposite states, even for a very short time period, should never be connected directly together. This can cause excessive current and damage to the device.

Two channels within the same device with the same input signals can be connected in parallel for additional output drive strength.

Unused outputs can be left floating. Do not connect outputs directly to V_{CC} or ground.

Refer to the *Feature Description* section for additional information regarding the outputs for this device.

Copyright © 2023 Texas Instruments Incorporated

8.2.2 Detailed Design Procedure

1. Add a decoupling capacitor from V_{CC} to GND. The capacitor needs to be placed physically close to the device and electrically close to both the V_{CC} and GND pins. An example layout is shown in the *Layout* section.
2. Ensure the capacitive load at the output is ≤ 50 pF. This is not a hard limit; it will, however, optimize performance. This can be accomplished by providing short, appropriately sized traces from the SN54SC2T74-SEP to one or more of the receiving devices.
3. Ensure the resistive load at the output is larger than (V_{CC} / $I_{O(max)}$) Ω. Doing so will not violate the maximum output current from the *Absolute Maximum Ratings*. Most CMOS inputs have a resistive load measured in MΩ; much larger than the minimum calculated previously.
4. Thermal issues are rarely a concern for logic gates; the power consumption and thermal increase, however, can be calculated using the steps provided in the application report, *CMOS Power Consumption and Cpd Calculation*.

8.2.3 Application Curves

Figure 8-2 shows an example of a single button press bouncing and causing the output to toggle multiple times. This will cause issues in the desired application. Figure 8-3 shows 4 button presses with an added debounce circuit, fixing the unwanted toggling and allowing for proper toggle switch operation.

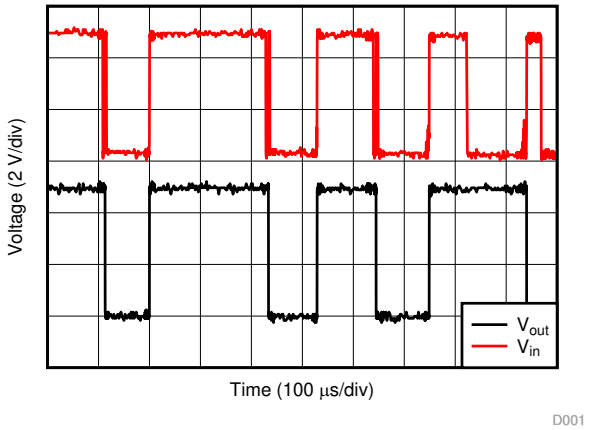


Figure 8-2. Circuit Response Without RC Debounce
V_{in}: = CLK Input, V_{out} := Q Output

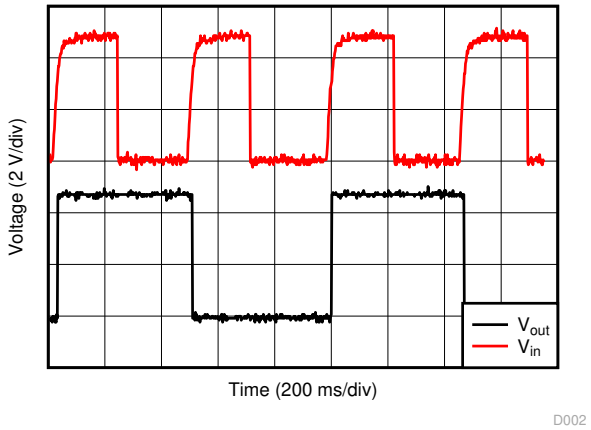


Figure 8-3. Circuit Response with RC Debounce
V_{in}: = CLK Input, V_{out} := Q Output

8.3 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1-µF capacitor is recommended for this device. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. The 0.1-µF and 1-µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results, as shown in the following layout example.

Copyright © 2023 Texas Instruments Incorporated

8.4 Layout

8.4.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices, inputs must never be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC}, whichever makes more sense for the logic function or is more convenient.

8.4.2 Layout Example

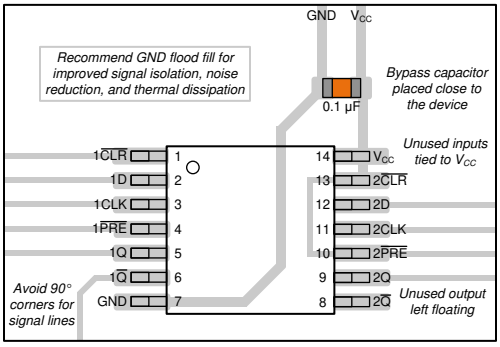


Figure 8-4. Example Layout for the SN54SC2T74-SEP

Copyright © 2023 Texas Instruments Incorporated

9 Device and Documentation Support

9.1 Documentation Support

9.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, *Implications of Slow or Floating CMOS Inputs* application report

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.
All trademarks are the property of their respective owners.

9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

TI Glossary	This glossary lists and explains terms, acronyms, and definitions.

10 Revisiqon History

DATE	REVSION	NOTES
November 2023	*	Initial Release

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Copyright © 2023 Texas Instruments Incorporated

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN54SC2T74MPWTSEP	Active	Production	TSSOP (PW) | 14	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	SC74SEP
SN54SC2T74MPWTSEP.A	Active	Production	TSSOP (PW) | 14	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	SC74SEP
V62/23632-01XE	Active	Production	TSSOP (PW) | 14	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	See SN54SC2T74MPWTSEP	SC74SEP
V62/23632-01XE	Active	Production	TSSOP (PW) | 14	250 | SMALL T&R	-	Call TI	Call TI	See SN54SC2T74MPWTSEP	

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

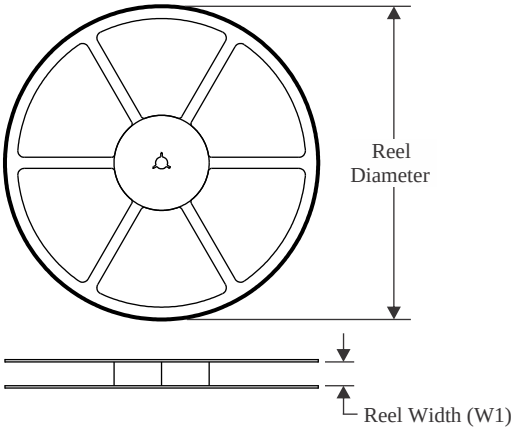
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

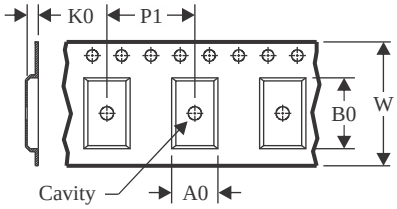
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

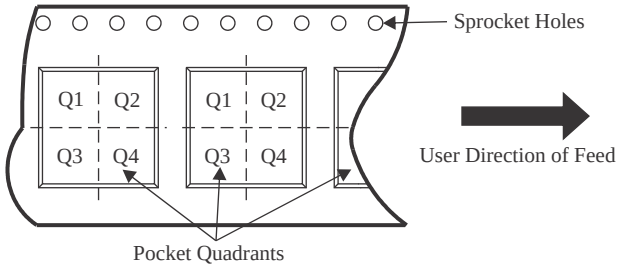


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

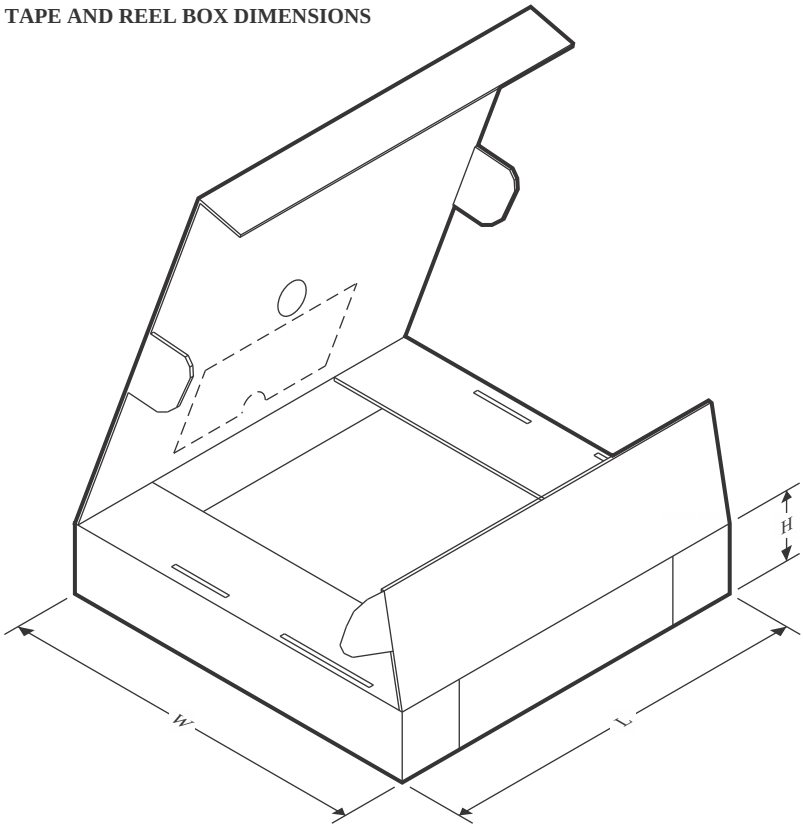
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN54SC2T74MPWTSEP	TSSOP	PW	14	250	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

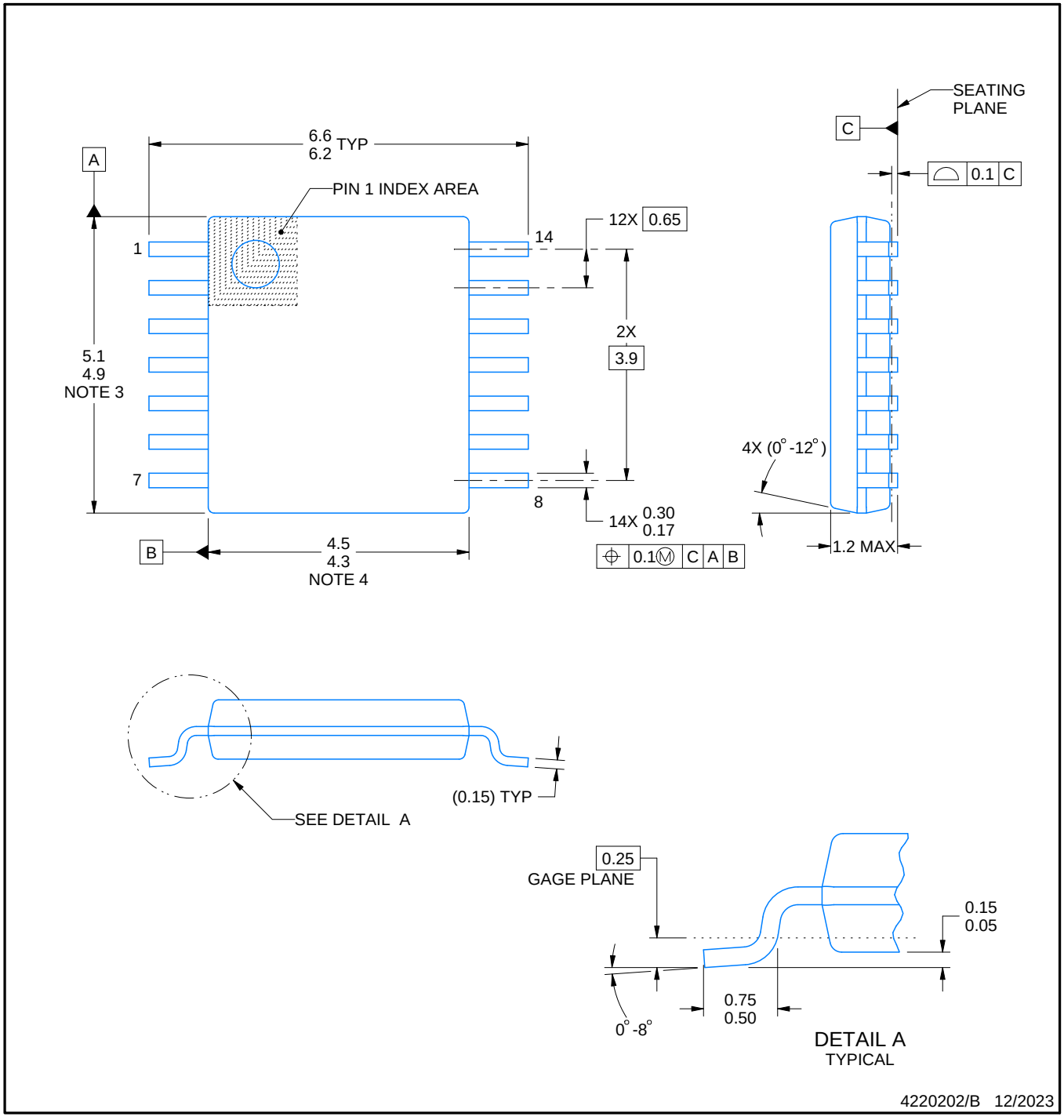
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN54SC2T74MPWTSEP	TSSOP	PW	14	250	353.0	353.0	32.0

PACKAGE OUTLINE

PW0014A

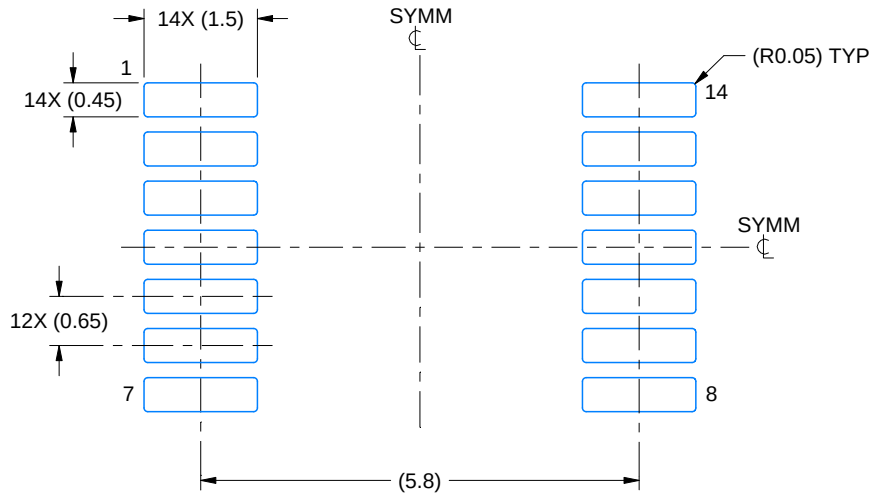
TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

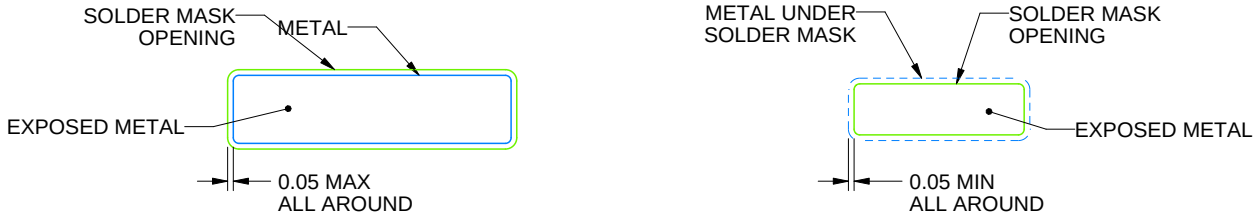


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

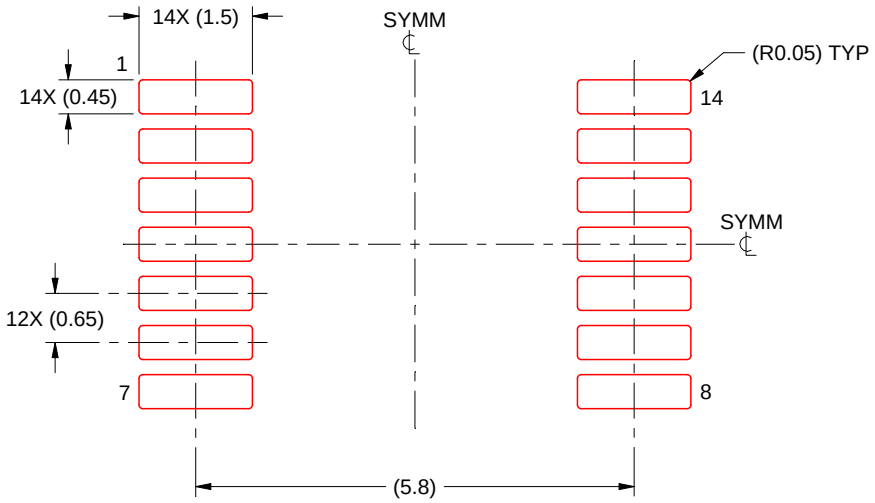


SOLDER MASK DETAILS

4220202/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220202/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES “AS IS” AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI’s products are provided subject to TI’s Terms of Sale, TI’s General Quality Guidelines, or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI’s provision of these resources does not expand or otherwise alter TI’s applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2026, Texas Instruments Incorporated

Last updated 10/2025